Ordering number : EN5864A

Red Laser Diode

DL-3147-161(-261)

Index Guided AlGaInP Laser Diode

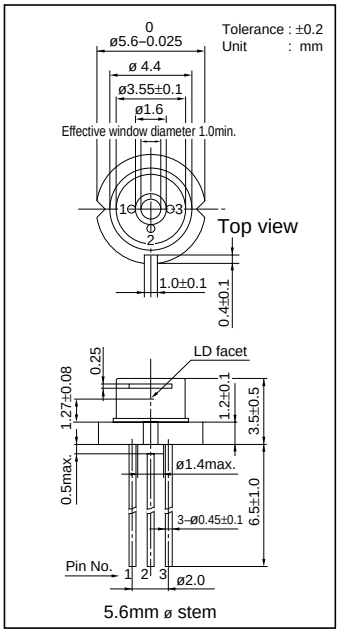
Overview

DL-3147-161(-261) is index guided 650 nm (Typ.) AlGaInP laser diode with low threshold current and high operating temperature. The low threshold current and high operating temperature are achieved by a strained multiple quantum well active layer. DL-3147-161(-261) is suitable for applications such as optical disc systems (DVD-ROM) and other optical information systems.

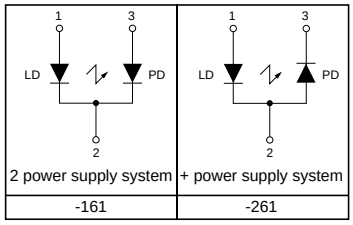
Features

- •Short wavelength : 650 nm (Typ.)
- •Low threshold current : Ith = 45 mA (Typ.)
- •High operating temperature : 5 mW at 70°C
- •TE mode°C

Package Dimensions



Electrical Connection



Absolute Maximum Ratings at Tc=25°C

Parameter		Symbol	Ratings	Unit
Light Output		Po	7	mW
Reverse Voltage	Laser	VR	2	V
	PIN		30	
Operating Temperature		Topr	–10 to +70	°C
Storage Temperature		Tstg	–40 to +85	°C

Electrical and Optical Characteristics at Tc=25°C

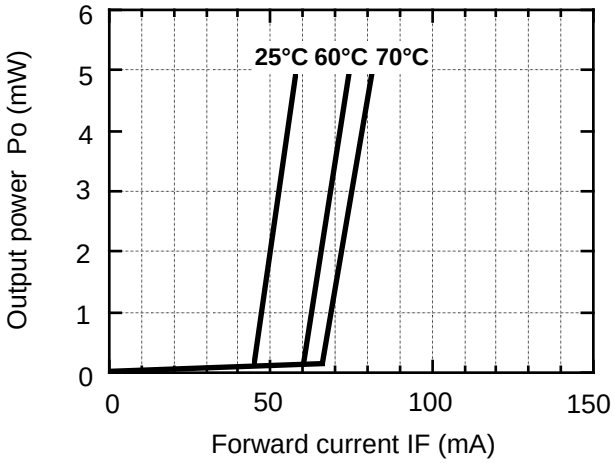
Parameter		Symbol	Condition	Min.	Typ.	Max.	Unit
Threshold Current		Ith	CW	–	45	65	mA
Operating Current		Iop	Po=5mW	–	60	80	mA
Operating Voltage		Vop	Po=5mW	–	2.2	2.5	V
Lasing Wavelength		λp	Po=5mW	–	650	660	nm
Beam ❋) Divergence	Perpendicular	θ⊥	Po=5mW	25	30	40	deg.
	Parallel	θ//	Po=5mW	6	7.5	10	deg.
Off Axis Angle	Perpendicular	Δθ⊥	–	–	–	±3	deg.
	Parallel	Δθ//	–	–	–	±2	deg.
Differential Efficiency		dPo/dIop	–	0.15	0.35	–	mW/mA
Monitoring Output Current		Im	Po=5mW	0.05	0.15	0.5	mA
Astigmatism		As	Po=5mW	–	8	–	μm

❋) Full angle at half maximum note : The above product specifications are subject to change without notice.

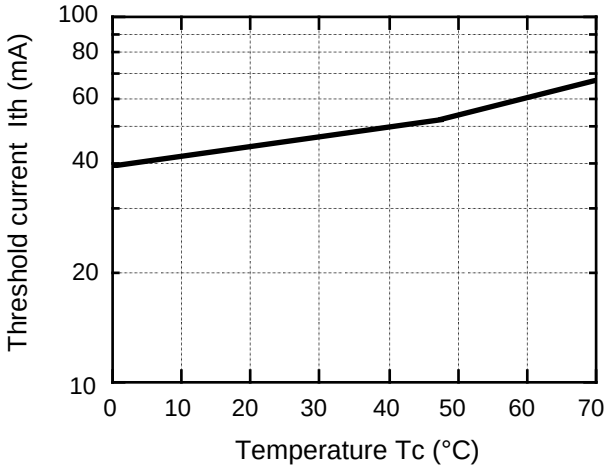
SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquarters
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

Characteristics

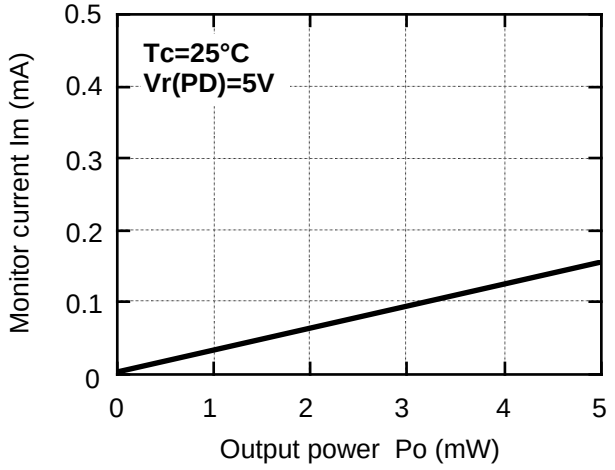
Output power vs. Forward current



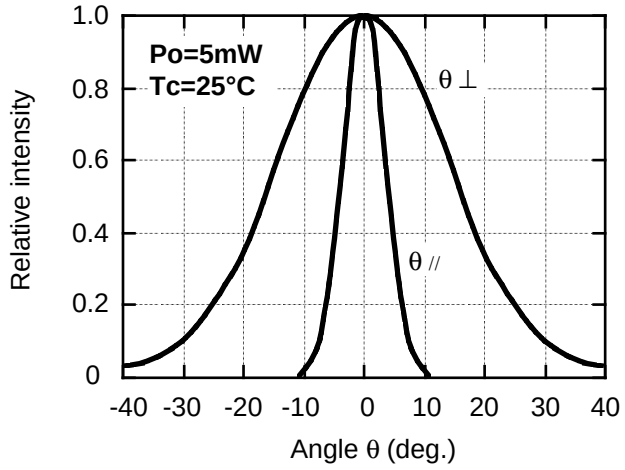
Threshold current vs. Temperature



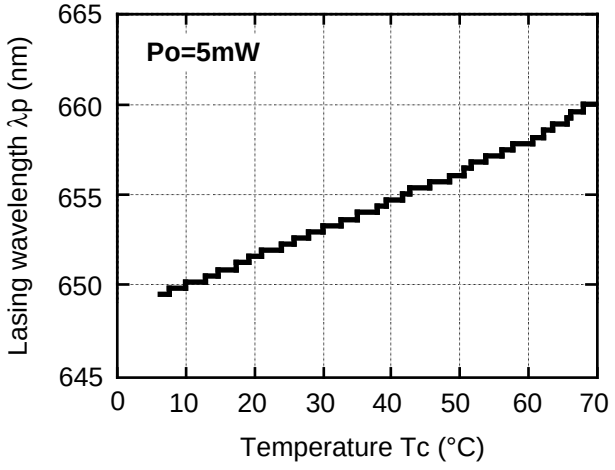
Monitor current vs. Output power



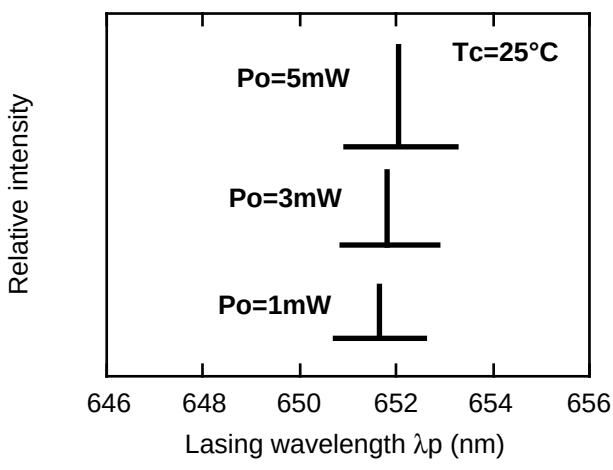
Beam divergence



Lasing wavelength vs. Temperature



Output power vs. Lasing wavelength



⚠ CAUTION

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Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

Manufactured by ; **Tottori SANYO Electric Co., Ltd.**
Electronics Device Bussiness Headquaters LED Division
5-318, Tachikawa-cho, Tottori City, 680-8634 Japan
TEL: +81-857-21-2137 FAX: +81-857-21-2161